

勝特力材料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw

2N3439 2N3440

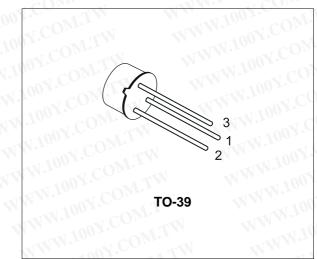
SILICON NPN TRANSISTORS

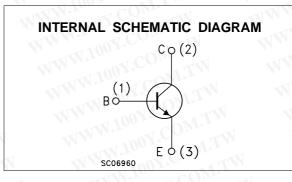
- STMicroelectronics PREFERRED SALESTYPES
- NPN TRANSISTOR

DESCRIPTION

The 2N3439 and 2N3440 are silicon epitaxial planar NPN transistors in jedec TO-39 metal case designed for use in consumer and industrial line-operated applications.

These devices are particularly suited as drivers in high-voltage low current inverters, switching and series regulators.





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Va	Unit	
	WW.100 × COM.	2N3439	2N3439 2N3440	
Vсво	Collector-Base Voltage (I _E = 0)	450	300	V
V _{CEO}	Collector-Emitter Voltage (I _B = 0)	350	250	V
V_{EBO}	Emitter-Base Voltage (I _C = 0)	7 1001		V
Ic	Collector Current	NL. 1 NWW.1		А
Ι _Β	Base Current	0.5		А
Ptot	Total Dissipation at $T_c \le 25$ °C 10			W
P _{tot}	Total Dissipation at $T_{amb} \le 50$ °C 1		1	W
T _{stg}	Storage Temperature	-65 t	°C	
Tj	Max. Operating Junction Temperature	2	00	°C

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THERMAL DATA

THERMA	DATA			
R _{thj-case}	Thermal Resistance Junction-case	Max	17.5	°C/W
R _{thj-amb}	Thermal Resistance Junction-ambier	Max	175	°C/W

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WTM

ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

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Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Ісво	Collector Cut-off Current ($I_E = 0$)	for 2N3439 V _{CB} = 360 V for 2N3440 V _{CB} = 250 V	1	WWW	20 20	μA μA
ICEO	Collector Cut-off Current ($I_B = 0$)	for 2N3439 V _{CE} = 300 V for 2N3440 V _{CE} = 200 V		WW	20 50	μΑ μΑ
I _{CEX}	Collector Cut-off Current (V _{BE} = -1.5V)	for 2N3439 V _{CE} = 450 V for 2N3440 V _{CE} = 300 V	N A	WW	500 500	μΑ μΑ
I _{EBO}	Emitter Cut-off Current $(I_C = 0)$	V _{EB} = 6 V	WT	4	20	μA
VCEO(sus)*	Collector-Emitter Sustaining Voltage	Ic = 50 mA for 2N3439 for 2N3440	350 250		MMM	V V
V _{CE(sat)} *	Collector-Emitter Saturation Voltage	$I_C = 50 \text{ mA}$ $I_B = 4 \text{ mA}$	M.TV		0.5	V
V _{BE(sat)} *	Base-Emitter Saturation Voltage	$I_{\rm C} = 50 \text{ mA}$ $I_{\rm B} = 4 \text{ mA}$	OM.T		1.3	V
h _{FE} *	DC Current Gain		40 30	TW	160	NWW
h _{FE}	Small Signal Current Gain	$I_C = 5 \text{ mA}$ $V_{CE} = 10 \text{ V}$ f = 1KHz	25	I.TW		WW
f⊤	Transition frequency	$I_C = 5 \text{ mA}$ $V_{CE} = 10 \text{ V}$ $f = 5 \text{MHz}$	15	M.T.V		MHz

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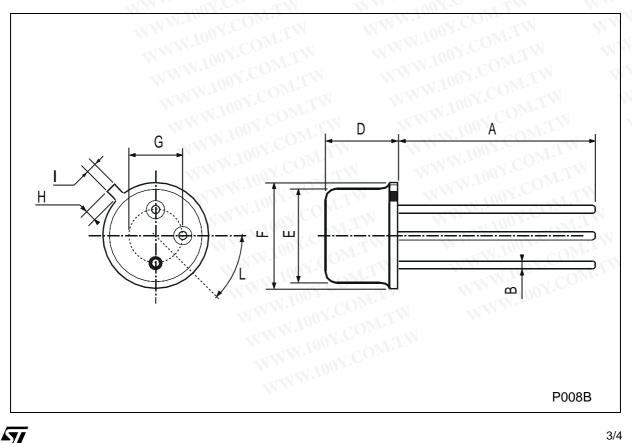
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TO-39 MECHANICAL DATA

DIM.	Man			inch			
WW.100Y	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
A .10	12.7		VW.100Y.C	0.500	WWW.	100 Y.COM	
В	DOY.COM.	N N	0.49	WT.MO	MMA	0.019	
D	100X.COM	LM I	6.6	COM.TW	V W	0.260	
EWW	1.100 Y.CO1	I.I.	8.5	Y.COM.T	V V	0.334	
FW	W.100X.CO	M.TW	9.4	JOY.COM.	V W1	0.370	
G	5.08	OMIT	WWW.	0.200	WIN	WWW.100	
н	WWW.100Y	COMPLEM	1.2	N.100Y.COT	WI.IW	0.047	
I	WWW.100	COM.TW	0.9	W.100Y.C	ONI.TW	0.035	
L	WWW.10	ON.COM.I	45° (t	yp.)	COM	WW	



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